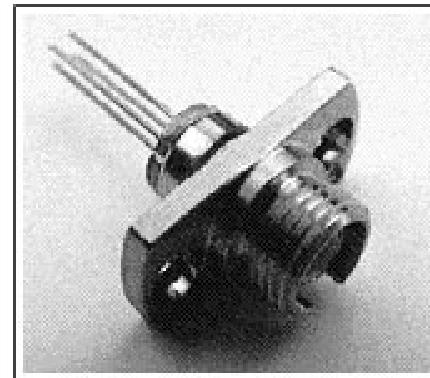


## 1300 nm Laser in Receptacle Package, Medium Power

STM 51007X

- Designed for application in fiber-optic networks
- Laser diode with Multi-Quantum Well structure
- Suitable for bit rates up to 1 Gbit/s
- Ternary photodiode at rear mirror for monitoring and control of radiant power
- Hermetically sealed subcomponents, similar to TO 18
- SM Receptacle with 2-hole flange



Type	Ordering Code	Connector/Flange
STM 51007G	Q62702-P3014	FC, 2-hole

### Maximum Ratings

Output power ratings refer to the SM fiber output. The operating temperature of the submount is identical to the case temperature.

Parameter	Symbol	Values	Unit
<b>Module</b>			
Operating temperature range at case	$T_C$	- 40 ... + 85	°C
Storage temperature range	$T_{stg}$	- 40 ... + 85	°C
Soldering temperature $t_{max} = 10$ s, 2 mm distance from bottom edge of case	$T_S$	260	°C

### Laser Diode

Direct forward current	$I_F \text{ max}$	120	mA
Radiant power CW	$\Phi_e$	2	mW
Reverse voltage	$V_R \text{ max}$	2	V

### Monitor Diode

Reverse voltage	$V_R \text{ max}$	10	V
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**Characteristics**

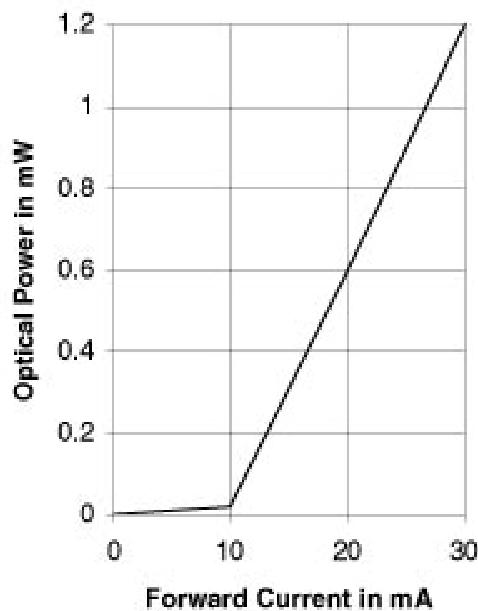
All optical data refer to a coupled 10/125 µm SM fiber,  $T_C = 25^\circ\text{C}$ .

Parameter	Symbol	Values	Unit
<b>Laser Diode</b>			
Optical output power	$\Phi_e$	> 1.2	mW
Emission wavelength center of range $\Phi_e = 0.5 \text{ mW}$	$\lambda$	1280 ... 1330	nm
Spectral bandwidth $\Phi_e = 0.5 \text{ mW}$ (RMS)	$\Delta\lambda$	< 5	nm
Threshold current (- 40 ... + 85 °C)	$I_{th}$	2 ... 45	mA
Forward voltage $\Phi_e = 0.5 \text{ mW}$	$V_F$	< 1.5	V
Radiant power at threshold	$\Phi_{eth}$	< 40	µW
Slope efficiency	$\eta$	20 ... 100	mW/A
Differential series resistance	$r_S$	< 8	Ω
Rise time/fall time	$t_R, t_F$	< 1	ns

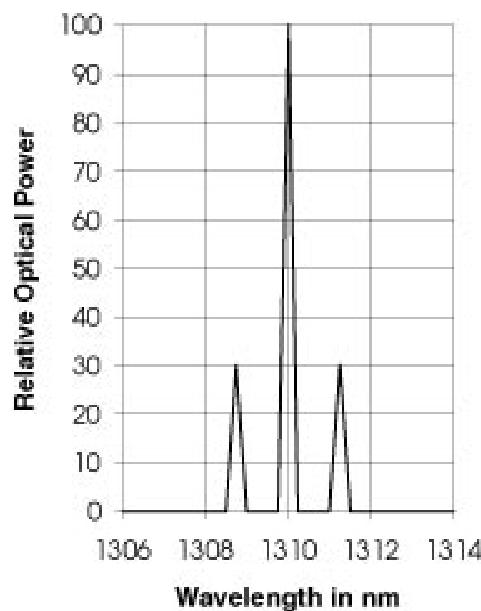
**Monitor Diode**

Dark current, $V_R = 5 \text{ V}, \Phi_e = 0$	$I_R$	< 500	nA
Photocurrent, $\Phi_e = 0.5 \text{ mW}$	$I_P$	100 ... 1000	µA

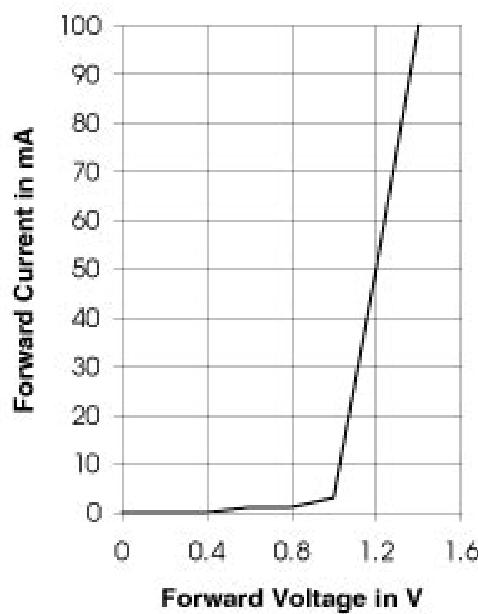
**Laser Diode**  
Radiant Power in Singlemode Fiber



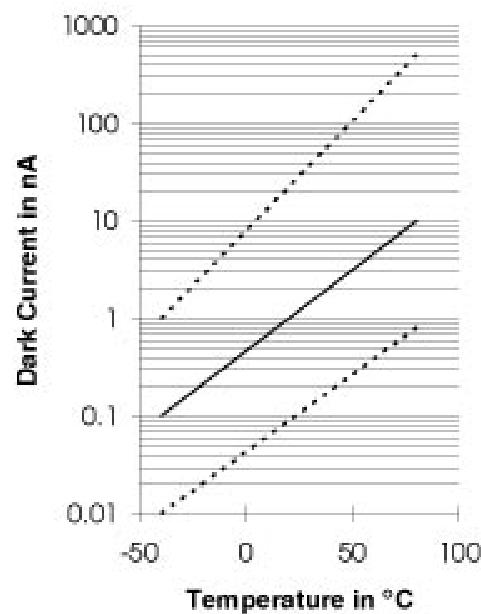
**Relative Radiant Power**  
 $\Phi_e = f(\lambda)$



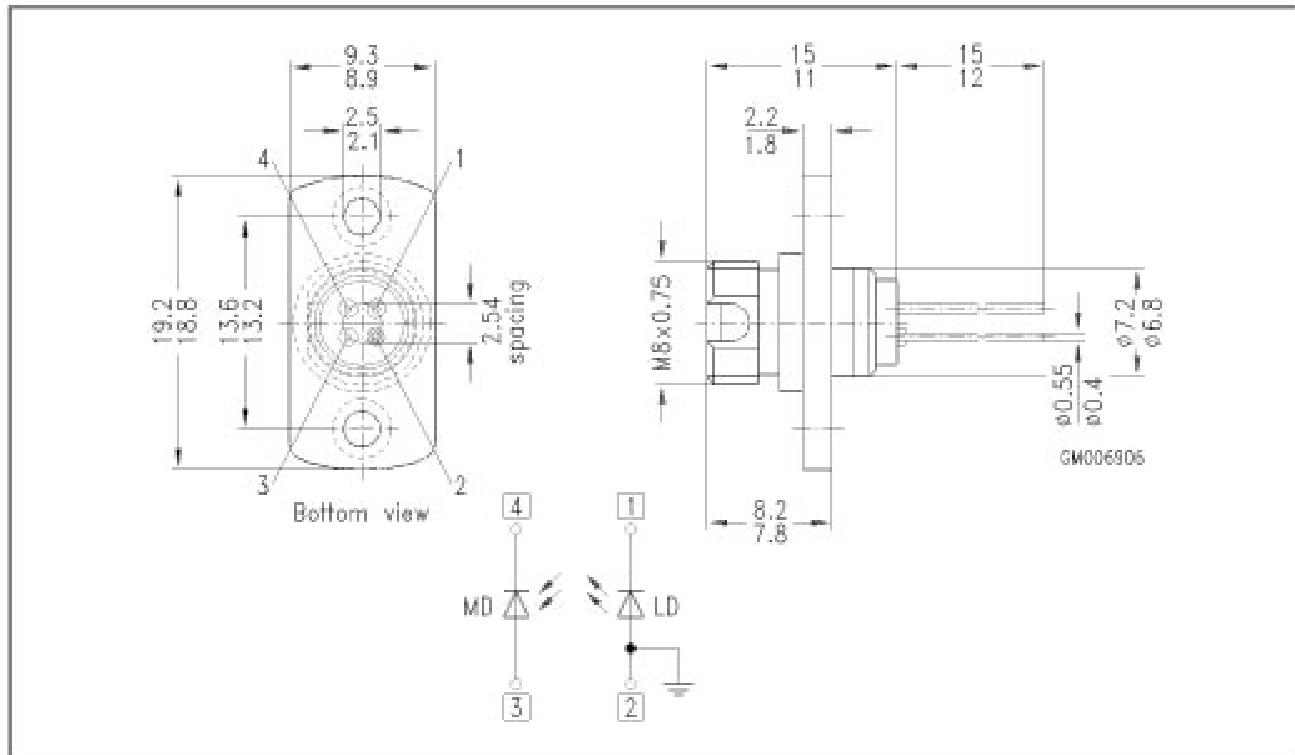
**Laser Forward Current**  
 $I_F = f(V_F)$



**Monitor Diode Dark Current  $I_R = f(T_A)$**   
 $\Phi_{port} = 0, V_R = 5 \text{ V}$



### **Package Outlines (Dimensions in mm)**



STM 51007X